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Photoluminescence of Y₃(Al, Ga)₅O₁₂:Ce³⁺ Nanoparticles by a Reverse Micelle Process

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Abstract Trivalent cerium-ion-doped $Y_3(Al, Ga)_5O_{12}$ nanoparticle phosphor nanoparticles were synthesized using the reverse micelle process. The Ce doped $Y_3(Al, Ga)_5O_{12}$ particles were obtained from nitrate solutions dispersed in the nanosized aqueous domains of a micro emulsion consisting of cyclohexane as the oil phase and poly(oxyethylene) nonylphenyl ether (Igepal CO-520) as the non-ionic surfactant. The crystallinity, morphology, and thermal properties of the synthesized $Y_3(Al, Ga)_5O_{12}$:Ce³⁺ powders were characterized by thermogravimetry-differential thermal analysis (TGA-DTA), X-ray diffraction analysis (XRD), scanning electron microscopy (SEM), and transmission electron microscopy. The crystallinity, morphology, and chemical states of the ions were characterized; the photo-physical properties were studied by taking absorption, excitation, and emission spectra for various concentrations of cerium. The photo physical properties of the synthesized $Y_3(Al, Ga)_5O_{12}$:Ce³⁺ powders were studied by taking the excitation and emission spectra for various concentrations of cerium. The average particle size of the synthesized YAG powders was below 1 μ m. Excitation spectra of the $Y_3Al_5O_{12}$ and $Y_3Al_{3.97}Ga_{1.03}O_{12}$ samples were 485 nm and 475 nm, respectively. The emission spectra of the $Y_3Al_5O_{12}$ and $Y_3Al_{3.97}Ga_{1.03}O_{12}$ were around 560 nm and 545 nm, respectively. $Y_3(Al, Ga)_5O_{12}$:Ce³⁺ is a red-emitting phosphor; it has a high efficiency for operation under near UV excitation, and may be a promising candidate for photonic applications.

Key words $\underline{Y_3(Al, Ga)_5O_{12}: Ce^{3+}}$ nanopowders, reverse micelle processing, phosphors powder.

1. Introduction

Yttrium aluminum garnet(Y₃Al_{5-x}Ga_xO₁₂:Ce³⁺, YAG) has been known as one of the most common phosphor host materials. The YAG phosphors doped with various rare earth elements are useful in a variety of display applications including cathode ray tube, low voltage field emission display, and backlight source. 1-4) Among them, cerium doped YAG(Y₃Al_{5-x}Ga_xO₁₂:Ce³⁺) is a comprehensively studied phosphor which is used as a yellow-emitting component for the production of a white light in the liquid crystal display(LCD) backlighting and the illumination light source. A combination of a blue light emitting diode (LED) and a yellow phosphor is a widely adopted type for a white light production because of its low fabrication cost and high luminous efficiency compared to the white LED mixed with red, green, and blue LEDs. 1,5,6) Which provides a basis to use YAG:Ce phosphor along with GaN LEDs to produce white light emitting diodes(WLEDs). Compared with traditional lighting, WLEDs have more advantage of high-energy efficiency, high reliability, long life, fast response and non-polluting. It is suggested that there would be a prosperous future in lamp market. The shift of Ce emission in a YAG has been manipulated by substituting dodecahedrally coordinated Y³⁺ site or octahedrally coordinated Al³⁺ site with different sizes of ions, wherein the crystal field splitting of the 5d levels of Ce³⁺ ion could be controlled by its coordination surrounding.⁷⁻⁹⁾ In this approach, there is an empirical rule that increasing the diameter of the ion on the dodecahedral site increases the crystal field splitting, while an diameter on the octahedral site has the reverse effect,9) thereby the red and blue shift of Ce emission can be realized. The formation process, spectral properties and the effects of Ga³⁺ concentration (x) on the luminescent properties of the activator ions (Ce³⁺) of the phosphor have been investigated.⁷⁻⁹⁾ Recently, much effort has been made to improve the brightness and resolution of projection. Y₃Al_{5-x}

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-Ga_xO₁₂ phosphor has been prepared using solid-state reaction technique, formed by partial substitution of Al in Y₃Al_{5-x}Ga_xO₁₂ with Ga, which exhibits considerably better saturation characteristics at higher density electron beam excitation than other Ce3+ activated garnet. Mono-phase cubic $Y_3Al_{5-x}Ga_xO_{12}$: Ce^{3+} (x = 0-5) phosphors with different Ga concentration were synthesized using nitrate-citrate sol-gel combustion process. The crystalline evolution and the particle size of the product were investigated and the influence of Ga concentration on the photoluminescence properties of the phosphors was reported.⁷⁻⁹⁾ Traditionally, YAG phosphors doped with activators are mainly synthesized by solid-state reaction techniques. 10,111) Phosphor powder can be fabricated through several methods, such as co-precipitation method, ^{12,13)} sol-gel, ^{14,15)} and combustion, 16,17) must of them requiring expensive equipment. Although less expensive equipment are needed for conventional reverse micelle process. The reverse micelle and micro-emulsion techniques have a further(potential) advantage which is yet to be investigated. That is, depending on the location within the phase diagram, the micro-emulsion may assume a variety of structures: spherical, cylindrical, lamellar, etc. Thus besides the size, one can even control the morphology of the particles. 18) The reverse micelle method has the unique advantage that the numerous nanoscale water pools existing in the micelle suspension are ideal microreactors for synthesizing nanoparticles.¹⁸⁾ In other words, this method allows the synthesis of particles with uniform small size and narrow size distribution because the reaction volume is limited to the size of the water droplets(typically a few nm). The object of this study was to investigate photoluminescence properties of the synthesized $Y_3Al_{5-x}Ga_xO_{12}$: Ce^{3++} (x = 0-5) nanoparticles by a reverse micelle process.

2. Experimental Procedure

Reverse micelle technique was used in this work to prepare Ce³⁺ activated YAG phosphor powders. The starting materials were: yttrium nitrate, Y(NO₃)₃·6H₂O (99.99 %, Daejung chemicals & metals Co., LTD); aluminum nitrate, Al(NO₃)₃·9H₂O (98 %, Sigma-Aldrich Chemical Co., LTD.); Gallium nitrate, Ga (99.9 %, Sigma-Aldrich Chemical Co., LTD.); cerium nitrate, Ce(NO₃)₃·6H₂O (98 %, Yakuri pure chemicals Co., LTD.); Igepal[poly (oxyethylene) nonylphenly (Igepal CO-520, Aldrich Chemical Co.); Cyclohexane (Sigma-Aldrich, HPLC grades); NH₄OH (28 % Daejung chemicals & metals Co., LTD), respectively. Fig. 1. illustrates the experimental procedure of the synthesized YAG powders by a reverse micelle process. The amount of 20.05 g of Igepal CO-520 was mixed with about 50 ml of cyclohexane by stirring for 3 h at room temperature. Yttrium nitrate(3 M) was added with continuous stirring.

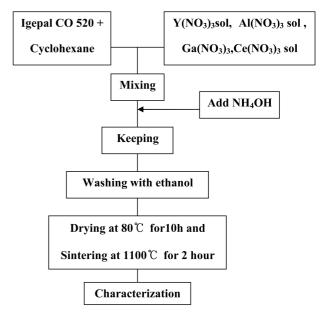


Fig. 1. Experimental procedure for the synthesis YAG powder by a reverse micelle process.

Aluminum nitrate(1 M) sol and gallium nitrate(1 M) sol was dissolved in 10 ml[rate $Al_{5-x}Ga_x$ (x = 0-5) mol] of distilled water by stirring for 2 h at room temperature. For preparing doped samples, the corresponding quantity of cerium nitrate(0.06 mol%) was added to the solution. Both solutions were mixed with 3.25-6.5 ml aqueous solution. NH₄OH 3.5 ml was injected into the microemulsion to accelerate the hydroxylation reaction of metal ions. Which were subsequently washed by ethanol to remove any residual surfactant and water and dried at 80 °C. The dried powder were then calcined at 1100 °C for 2 h. with a heating rate of 5 °C/min. The crystal structures of powders were characterized by using X-ray diffraction(XRD, X'pert, MPD, Philips, Nedelland) in the 2θ range of 10-80°, with a counting time of 1 s for each step size of 0.04°. Scanning electron microscopy(SEM) images were taken on a JEOL JSM-5610 field emission scanning electron microscope. The luminescence spectra of Ce³⁺ substituted for Y³⁺ in YAG have been measured on samples made-up at different $Y_3Al_{5-x}Ga_xO_{12}$: Ce^{3+} (x = 0-5) rate. The synthesized powder was pressed into a pellet for the absorption and the photoluminescence(PL) measurements. PL spectra were taken with a steady-state fluorescence system with a 450-W Xe lamp. The excitation light from the Xe lamp(SHIMADZU, RF-5301PC).

3. Results and Discussion

Fig. 2 shows the XRD patterns of $Y_3Al_5O_{12}$: Ce^{3+} and $Y_3Al_{3.97}Ga_{1.03}O_{12}$: Ce^{3+} calcined at 1100 °C for 2 h. The diffraction pattern of the sample showed that all the peaks of the $Y_3Al_5O_{12}$ and $Y_3Al_{3.97}Ga_{1.03}O_{12}$ phase, which

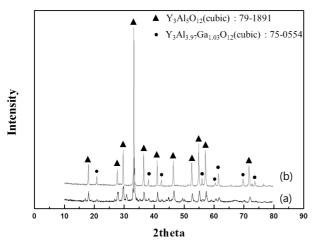


Fig. 2. X-ray diffraction of synthesized YAG; (a) $Y_3Al_5O_{12}$: Ce^{3+} and (b) $Y_3Al_{3.97}Ga_{1.03}O_{12}$: Ce^{3+} .

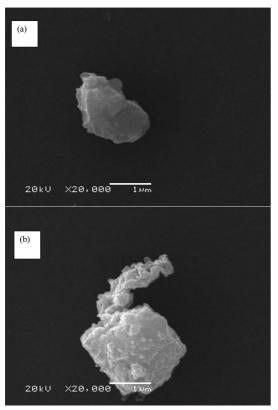


Fig. 3. SEM micrographs of YAG: Ce^{3+} particles calcined at 1100 °C for 2 h; (a) $Y_3Al_5O_{12}$: Ce^{3+} and (b) $Y_3Al_{3.97}Ga_{1.03}O_{12}$: Ce^{3+} .

is in good agreement with JCPDS Card (no. 79-1891) and (no. 75-0554), respectively. The luminescence properties of phosphor particles depend on the morphology of the particles such as size, size distribution, shape and defects. Fig. 3 shows scanning electron micrographs of the synthesized Y₃Al₅O₁₂:Ce³⁺ and Y₃Al_{3.97}Ga_{1.03}O₁₂:Ce³⁺ calcined at 1100 °C for 2 h. The average particles size of the synthesized powders by measuring linear intercept method

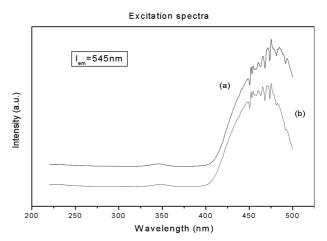


Fig. 4. Photoluminescence excitation spectra of the synthesized powders; (a) $Y_3AI_5O_{12}$:Ce³⁺ and (b) $Y_3AI_{3.97}Ga_{1.03}O_{12}$:Ce³⁺.

was below 1 μ m. Fig. 4 shows the excitation spectra for the Ce³⁺ emission 475 nm in the YAG phosphors. Each excitation spectrum of Y₃Al₅O₁₂:Ce³⁺ and Y₃Al_{3.97}Ga_{1.03}O₁₂:Ce³⁺ were around 475 nm and 485 nm, respectively, which corresponds to the electronic transitions from the ground state of Ce³⁺ to the crystal field splitting bands of excited state of Ce³⁺ ion.

The emission of Ce^{3+} is ascribed to the electron transitions from the lowest crystal-splitting component of $5D^1$ level to the ground state of Ce^{3+} ($2F_{5/2}$, $2F_{7/2}$). Modification of the YAG chemical composition with foreign ions is a common strategy for tailoring the Ce^{3+} 5d-4f emission. The excitation of the luminescence of Ce^{3+} is done by laser, and trivalent cerium is excited to a 5d state. In the first case, the excited $(Ce^{3+})^*$ ion emits a 5d-4f scintillation photon hv

$$via(Ce^{3+})^* \rightarrow Ce^{3+} + hv_s \tag{1}$$

Ce³⁺ may also lose its 4f electron to form Ce⁴⁺ either by direct ionization or by capturing a hole created in the valence states of the anions. Usually, the ionization holes are sequentially trapped on the luminescent ions, as indicated below, because Ce³⁺ ions act as hole traps in the present materials.

$$Ce^{3+} + h \rightarrow Ce^{4+} \tag{2}$$

The process may be prompt if the hole is nearby or delayed if the hole diffuses to the vicinity of cerium site. The resulting Ce⁴⁺ may then capture an electron,

$$Ce^{4+} + e \rightarrow (Ce^{3+})^*$$
 (3)

and subsequently decay by the process in eq. 3. Ce³⁺ emission in a YAG host can be tuned by partially

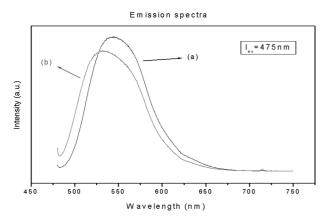


Fig. 5. Photoluminescence emission spectra(PL) of the synthesized powders with the excitation at 475 nm; (a) $Y_3Al_5O_{12}$: Ce^{3+} and (b) $Y_3Al_{3.97}Ga_{1.03}O_{12}$: Ce^{3+} .

or entirely substituting Al^{3+} site with different types of cation respectively, substitution of Al^{3+} with larger Ga^{3+} ion results in blue-shifted Ce emission at the expense of emission efficiency. Fig. 5 shows the emission spectra of nano-scale powders of $Y_3Al_{5-x}Ga_xO_{12}$: Ce^{3+} prepared at 1100 °C for 2 h in air with different (x = 0, x = 1.03) concentrations. The emission spectra of the $Y_3Al_5O_{12}$ and $Y_3Al_{3.97}Ga_{1.03}O_{12}$ were around 560 nm and 545 nm, respectively. It is clear from the figure that the emission intensity decreased from without Ga to with 1.03 Ga.

4. Conclusions

We studied the optical properties of Ce³⁺ doped Y₃(Al, Ga)₅O₁₂ to understand the principle of phosphors active under NUV excitation. We synthesized Y₃(Al, Ga)₅O₁₂: Ce³⁺ phosphors by reverse micelle process. The structure and the basic properties of the phosphors were characterized. The diffraction pattern of the sample showed that all the peaks of the Y₃Al₅O₁₂ and Y₃Al_{3.97}Ga_{1.03}O₁₂ phase, which is in good agreement with JCPDS Card (no. 79-1891) and (no. 75-0554), respectively. The average size of the synthesized Y₃(Al, Ga)₅O₁₂:Ce³⁺ powders was below 1 µm. The optical properties were studied by taking excitation and emission spectra at room temperature. Excitation spectrum of the Y₃Al₅O₁₂ and Y₃Al_{3.97}Ga_{1.03}O₁₂ were around 475 nm and 485 nm, respectively. The emission spectra of the $Y_3Al_5O_{12}$ and $Y_3Al_{3.97}Ga_{1.03}O_{12}$ were around 560 nm and 545 nm, respectively.

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